Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAT2165N Silicon N Channel Power MOS FET

Power Switching

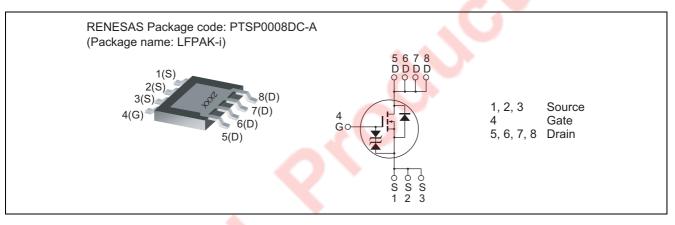
REJ03G1680-0300
Rev.3.00
May 27, 2008

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance

 $R_{DS(on)} = 2.8 \text{ m}\Omega \text{ typ.}$ (at $V_{GS} = 10 \text{ V}$)

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	ID	55	А
Drain peak current	Note1 I _{D(pulse)}	220	А
Body-drain diode reverse drain current	I _{DR}	55	А
Avalanche current	I _{AP} Note 2	30	А
Avalanche energy	E _{AR} Note 2	90	mJ
Channel dissipation	Pch Note3	30	W
Channel to case thermal resistance	θch-C	4.17	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 $\mu s,$ duty cycle \leq 1%

2. Value at Tch = 25°C, Rg \geq 50 Ω

3. Tc = 25°C

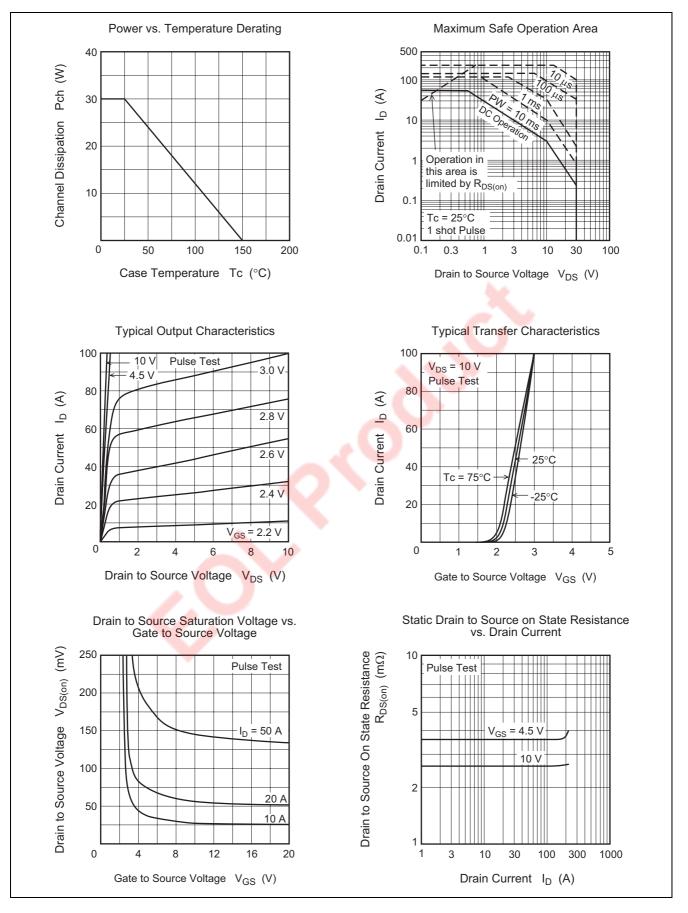
Electrical Characteristics

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	30	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V _{(BR)GSS}	±20	—	—	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}		—	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	—	1	μΑ	$V_{DS} = 30 V, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.0	—	2.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	2.8	3.6	mΩ	$I_D = 27.5 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
resistance	R _{DS(on)}	_	3.7	5.6	mΩ	$I_D = 27.5 \text{ A}, V_{GS} = 4.5 \text{ V}^{Note4}$
Forward transfer admittance	y _{fs}	60	100	—	S	$I_D = 27.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	5180	—	pF	V _{DS} = 10 V
Output capacitance	Coss		1200	—	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss		380	_	pF	
Gate resistance	Rg		0.5	_	Ω	
Total gate charge	Qg	_	33	—	nc	V _{DD} = 10 V
Gate to source charge	Qgs	_	15	—	nc	V _{GS} = 4.5 V
Gate to drain charge	Qgd	_	7.1	—	nc	I _D = 55 A
Turn-on delay time	t _{d(on)}	_	13	—	ns	V _{GS} = 10 V, I _D = 27.5 A
Rise time	tr	_	65	—	ns	
Turn-off delay time	t _{d(off)}		60		ns	
Fall time	t _f		9.5	-	ns	
Body–drain diode forward voltage	V _{DF}		0.81	1.06	V	$I_F = 55 \text{ A}, V_{GS} = 0^{Note4}$
Body-drain diode reverse recovery	t _{rr}	_	40		ns	$I_F = 55 \text{ A}, V_{GS} = 0$
time						di _F / dt = 100 A/ μs

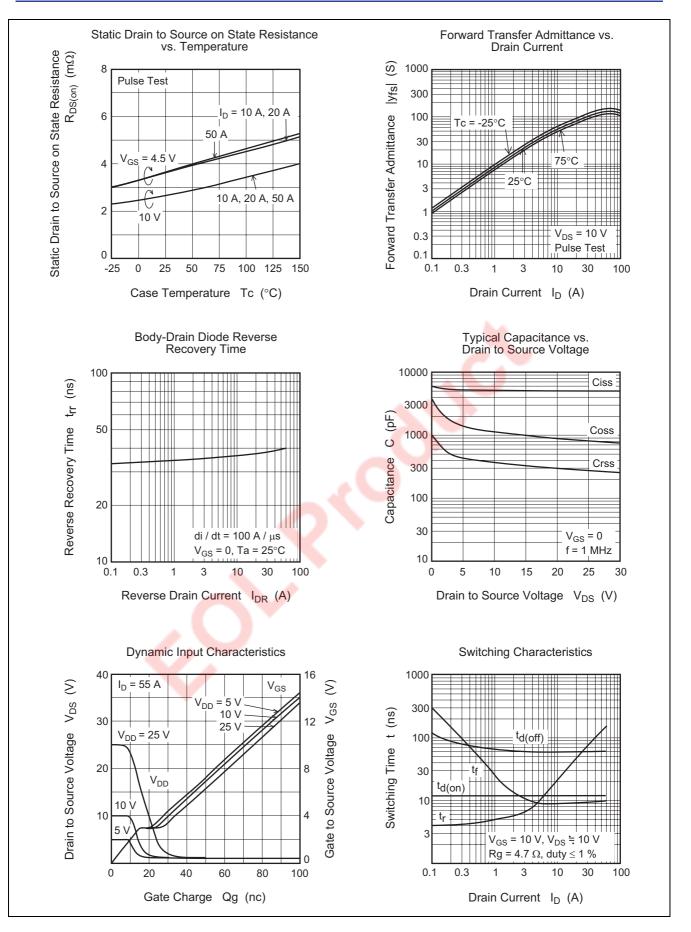
Notes: 4. Pulse test

i,C

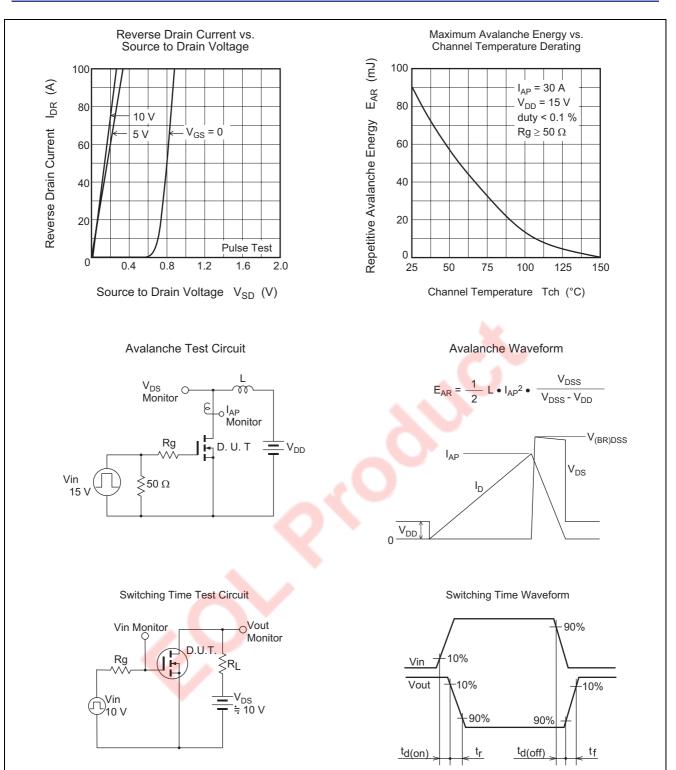
Main Characteristics



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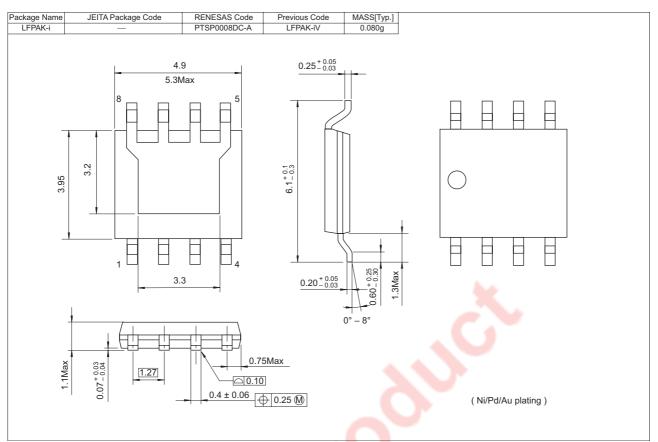


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Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
HAT2165N-EL-E	2500 pcs 📃 📃	Taping

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